WJ-861X RECEIVER

APPENDIX F

WJ-861X WIDEBAND IF OUTPUT AMPLIFIER (WBO) OPTIONS

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WARNING

This equipment utilizes voltages which are potentially dangerous and may be fatal if contacted. Exercise extreme caution when working with the equipment with any protective cover removed.

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APPENDIX F

WJ-861X WIDEBAND IF OUTPUT AMPLIFIER (WBO) OPTIONS

F.1 GENERAL DESCRIPTION

The Wideband IF Output Amplifier (WBO) option provides the 21.4 MHz IF signal at the rear panel connector J20. There are two types of WBO options. The output signal of Type 724013-1, associated with the WJ-861X/WBO option, has a constant bandwidth of at least 4.0 MHz, regardless of the selected IF bandwidth. The output signal of Type 724013-2, associated with the WJ-861X/WBO-2 option, has a bandwidth of 6 MHz minimum, regardless of the selected IF bandwidth. The output level for both types is maintained at -30 dBm into a 50Ω load. Internal automatic gain control (AGC) circuitry provides 40 dB of gain control. This enables the WBO level, at J20, to be maintained at -30 dBm ± 6 dB with input level changes of up to 40 dB.

F.2 INSTALLATION

The Type 724013-1 or 724013-2 Wideband IF Output Amplifier mounts in the compartment directly below the Signal Monitor compartment, on the underside of the receiver. Four mounting screws secure the module to the receiver deck and three cables provide all electrical connections. Installation of the Type 724013-1 or 724013-2 Wideband IF Output Amplifier is performed as follows:

- 1. Remove the bottom cover of the receiver exposing the compartment that accepts the Wideband IF Amplifier. This is the compartment directly forward of the receiver Power Distribution circuitry (A1).
- 2. Disconnect P71 of cable W31 and P69 of cable W30 from connector CP1.
- Connect P69 of cable W30 to connector J2 of the Wideband IF Output Amplifier module.
- Connect P71 of cable W31 to connector J1 of the Wideband IF Output Amplifier module.
- 5. Position the Wideband IF Output Amplifier against the receiver deck and align the four mounting holes on the module with the four threaded studs on the deck. Using 4-40 X 1/4 machine screws and appropriate flat and lock washers, secure each of the four mounting points to the receiver deck.
- 6. Plug connector A9P1 of the Wideband IF Output Amplifier to J2B, on the RF/IF Motherboard (A3). Position the connector such that pin 1 of A9P1 mates with J2B pin 4 and A9P1 pin 3 mates with J2B pin 6.
- 7. Re-install the receiver bottom cover.

F.3 OPERATION

The Type 724013-1 or 724013-2 Wideband IF Output Amplifier is operational at all times, when the receiver is powered. No additional operating procedures are required.

F.4 <u>CIRCUIT DESCRIPTION</u>

F.4.1 FUNCTIONAL DESCRIPTION

The input to the Type 724013-1 or 724013-2 Wideband IF Output Amplifier (A9) is taken from the receiver's 2nd Converter (A3A7) prior to band-limiting by the 21.4 MHz IF Amplifier. This 6 MHz wide signal band enters the Wideband IF Amplifier at connector J2. The signal is then amplified by a gain-controlled amplifier (Q1) and a 20 dB fixed-gain amplifier (U1). From the output of the amplification stages, the signal is applied to the output of the subassembly via an RFI filter. This filter passes a frequency spectrum of at least 3.5 MHz, about the 21.4 MHz IF center frequency for the Type 724013-1 board and a frequency spectrum of at least 6 MHz for the Type 724013-2 board.

The output level of the module, at connector J1, is maintained at a level of $-30~\mathrm{dBm}$ by an on-board AGC circuit. A sample of the output signal is amplified by a 20 dB amplifier (U2) and applied to the detection circuitry of U3. This AGC circuit provides a dc voltage ranging from +.7 to -6.3 Vdc, controlling the gain of the input amplifier (Q1). The AGC loop permits the output to be maintained at $-30~\mathrm{dBm}$ $\pm 6~\mathrm{dB}$ with input level changes of up to 40 dB at the input to the module (J2).

F.4.2 DETAILED CIRCUIT DESCRIPTION

F.4.2.1 Type 724013-1 and 724013-2 Wideband IF Output Amplifier (A9)

The reference designation for this subassembly is A9. Refer to Figure F-3 for the Type 724013-1 and Type 724013-2 Wideband IF Output Amplifier schematic diagram.

The wideband IF signal, centered about 21.4 MHz enters this subassembly at input connector J2 and is coupled across C1 to gate #1 (pin 3) of transistor Q1. Resistors R7 and R3 form a voltage divider to bias gate #1. Gate #2 (pin 2) of Q1 receives bias from the voltage divider formed by R6, R2 and CR1, with resistor R5 providing a means of injecting the AGC voltage to alter the bias at gate #2 for control of module gain. At low signal levels, the divider formed by R6, R2 and forward biased diode CR1 sets the bias at gate #2 to approximately +4 Vdc, causing Q1 to operate at maximum gain. With increases in signal level, the AGC circuitry applies a negative-going voltage to the anode of CR1, via R5. This voltage varies from 0, when the input signal is at AGC threshold, to -6.3 Vdc, when the signal level is at 40 dB above AGC threshold. When the AGC voltage is sufficiently negative overcoming the forward bias on CR1, CR1 cuts off and is effectively removed from the circuit. The bias at pin 2 of Q1 is then determined by the voltage divider comprised of R6, R2 and R5, connected between the +15 Vdc supply and the output of the AGC circuitry. This arrangement permits the bias on Q1 to be varied between its +4 Vdc maximum gain point to a slightly negative voltage setting the gain of Q1 to minimum, in accordance with the level of the incoming signal. The output of Q1 is developed across the tank circuit comprised of L1, C5 and R10. L1 and C5 center the output response about the 21.4 MHz IF center frequency and R10 lowers the "Q" of the tuned Circuit broadening the bandwidth of the tank. Capacitor C21 prevents the flow of dc current through R10.

From the output circuitry of Q1, the signal is applied, via C6, to the input of broadband amplifier U1. This amplifier provides a gain of approximately 20 dB and applies the signal, via R14, to the output of the subassembly and via C22 to the AGC detector circuitry. The operating voltage for U1 is provided at pin 2 of U1 via VR1. VR1 drops the +15 Vdc supply voltage to 6.8 Vdc. Bias at pin 7 is provided by the voltage divider formed by R12 and potentiometer R11, with R11 permitting adjustment of the gain of U1. The output signal at U1 pin 3, is coupled across C9 and developed across output load resistor R13.

The output of U1 is applied to the output connector (J1) via resistor R14 and the bandpass filter comprised of C3 through C10 and inductors L1, L2 and L3. L1, along with capacitors C3, C4 and C5, form a parallel-resonant circuit with a 21.4 MHz center frequency. The input to this circuit is applied at the junction of C3, C4 and C5 matching the input impedance of the tank circuit to the output of U1. The signal is then applied, via the 21.4 MHz series-resonnant circuit comprised of L2 and C6, to a second parallel-resonant tank. In the Type 724013-1, this second parallel-resonant tank consists of L3 and C7 through C10. In the Type 724013-2, this second parallel tank consists of L3 and C8 thru C10. This combination of tank circuits form a bandpass filter which provides a 3.5 MHz (minimum) 3 dB bandwidth about the 21.4 MHz center frequency in the Type 724013-1 and a 6 MHz 3 dB bandwidth about 21.4 MHz with the Type 724013-2. The output is taken from the junction of C8, C9 and C10 providing an output impedance, at J1, of 50Ω .

A sample of the output of U1 is applied to the AGC circuitry of the Wideband IF Output Amplifier controlling the gain of the subassembly. This signal is coupled across C22 and is applied to the amplifier U2. U2 provides 20 dB of amplification, as determined by the voltage divider formed by resistors R15 and R16, and applies its amplified output to the primary of transformer T1. The signal is then coupled across T1 and applied to the detector circuit comprised of CR2, C17 and R20. This circuit strips the 21.4 MHz component from the signal and produces a video signal impressed on a dc level that is representative of the strength of the input signal. Integrated circuit U3A amplifies the detected signal and applies the signal to a peak detector comprised of CR3, C18, R26 and R23. The fast charge and slow discharge time of this detector produces a dc level that is representative of the peak amplitude of the received signal. This dc level is then applied to inverter amplifier U3B producing the gain-control voltage for the subassembly.

The voltage divider formed by R25 and potentiometer R24 sets the point at which the AGC voltage begins controlling the subassembly gain. When the detected voltage at pin 6 of U3B increases above the level at pin 5, the output of U3B begins to produce a negative-going output voltage. This output voltage is then applied to transistor Q1 decreasing the subassembly gain to provide the proper output level. Resistor R21 and regulator VR3 limit the extremes of the AGC voltage to between +.7 and -6.3 Vdc. Under strong signal conditions, VR3 permits the AGC voltage to increase until it reaches its maximum of -6.3 Vdc. At that point VR3 begins conducting to prevent any further AGC voltage increase. Under weak signal conditions, the output of U3B is a positive voltage which is felt at the anode of VR3. VR3 is forward biased at this time and prevents the AGC voltage from increasing to more than 0.7 Vdc.

F.5 ALIGNMENT PROCEDURE

When performing the following alignment procedure, the Wideband IF Output Amplifier mounting screws should be removed permitting access to the adjustments on the underside of the subassembly. The alignment should be performed utilizing the test equipment listed or equivalents.

Equipment	Description	Туре		
Sweep Generator Step Attenuator Detector Oscilloscope 20 dB amplifier RF Millivoltmeter	0-1200 MHz 0-80 dB 50 ohm DC to 35 MHz 6 MHz minimum bandwidth Probe "T" Adapter 50 ohm Termination	Wavetek 2001 TF-10141 (WJ CET) HP-423A Tektronic T935 Boonton 92B Boonton 91-12F Boonton 91-14A Boonton 91-15A		

F.5.1 TYPE 724013-1 AND 724013-2 WIDEBAND IF OUTPUT AMPLIFIER ALIGNMENT

- 1. Remove the cover from the subassembly and disconnect the jumper from between terminals E3 and E1.
- Connect the test equipment as illustrated, with the 20 dB amplifier connected at terminal E3.
- 3. Set the sweep generator to sweep at least 6 MHz about a 21.4 MHz center frequency at an output level of -10 dBm. Activate the 21.4 MHz marker.
- 4. Set the attenuator for 55 dB of attenuation.
- 5. Preset R11 to midrange and R24 to its maximum CW position.

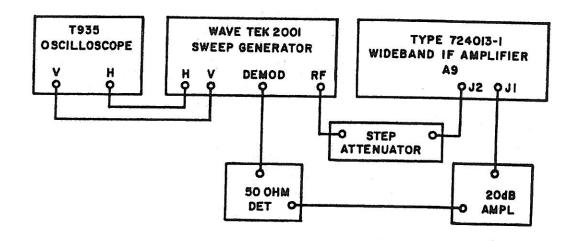


Figure F-1. Wideband IF Output Amplifier Alignment Equipment Connections

- 6. Adjust the oscilloscope controls to produce a suitable display of the output response, with the 21.4 MHz marker at the center of the display.
- 7. Adjust C5 centering the wideband response about the 21.4 MHz marker.
- 8. Disconnect the 20 dB amplifier from E3 and reconnect the jumper between E1 and E3.
- 9. Temporarily replace the subassembly cover and attach the 20 dB amplifier to output connector J1.
- 10. Activate the 1 MHz markers on the sweep generator.
- 11. From the underside of the Type 724013-1 subassembly, adjust L1, L2 and C7 to obtain the following response:

Center Frequency:

21.4 MHz

3 dB Bandwidth:

3.5 MHz, minimum; 5 MHz typical

Ripple:

1 dB or less

From the underside of the Type 724013-2 subassembly, adjust L1, L2 and L3 to obtain the following response:

Center Frequency:

21.4 MHz

3 dB Bandwidth:

6.0 MHz, minimum

Ripple:

1 dB or less

- 12. Remove the module cover and disconnect the 20 dB amplifier from J1.
- 13. Set the generator to produce a fixed 21.4 MHz CW output.
- 14. Connect the RF millivoltmeter and 50Ω load at J1.
- 15. On Type 724013-1 boards, adjust R11 to produce a -31 dBm indication on the RF millivoltmeter. On Type 724013-2 boards, adjust R11 to produce a -30 dBm (±3 dB) indication on the RF millivoltmeter.
- 16. Adjust R24 CCW until the indication on the millivoltmeter just begins to decrease. When adjusting R24, the meter indication may rapidly decrease and then spring back. Continue adjusting R24 until no spring back occurs and set R24 to the point where the level just began to decrease.
- 17. Set the attenuator for -15 dB of attenuation, while observing the RF millivoltmeter indication. The level should not change by more than 6 dB from the level set in step 15. If a change of greater than 6 dB is observed, repeat step 16.
- 18. Reinstall the subassembly cover and install the subassembly into the receiver.

F.6 PARTS LIST

F.6.1 TYPE 724013-1, WIDEBAND IF OUTPUT AMPLIFIER

REF DESIG PREFIX A9

REF DESIG	DESCRIPTION	QTY PER ASSY	MANUFACTURER'S PART NO.	MFR. CODE	RECM VENDOR
A1 C1 C2 C3 C4 C5 C6 C7 C8 C9 C10 J1 J2 L1 L2 L3 P1	Revision D Wideband IF Output Amplifier Capacitor, Ceramic, Feedthru: 1000 pF, GMV, 500 V Same as C1 Capacitor, Mica, Dipped: 300 pF, 2%, 500 V Capacitor, Ceramic, Standoff: 100 pF, 10%, 500 V Capacitor, Mica, Dipped: 510 pF, 2%, 500 V Capacitor, Ceramic, Tubular: 7.5 pF, ±0.5 pF, 500 V Capacitor, Variable, Air: 0.8-10 pF, 250 V Capacitor, Mica, Dipped: 430 pF, 2%, 500 V Same as C3 Same as C4 Connector, Receptacle Connector, Receptacle Coil, Variable Coil, Variable Coil, Fixed Plug, Assembly	1 2 2 2 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1 1	270465-1 54-794-009-102W CM05FD301G03 54-803-009-101K DM15-511G 301-000C0H0-759D 5202 DM15-431G 1012-1511-000 1004-7511-002 558-7107-06 558-7107-24 21210-74 370434-4	14632 33095 81349 33095 72136 72982 91293 72136 19505 19505 71279 71279 14632 14632	

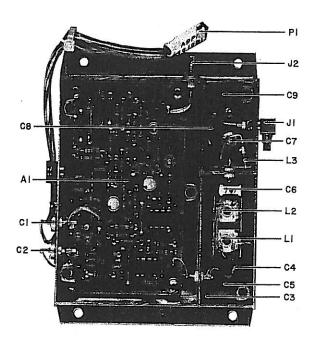


Figure F-2. Type 724013-1, -2 Wideband IF Output Amplifier, (A9), Location of Components

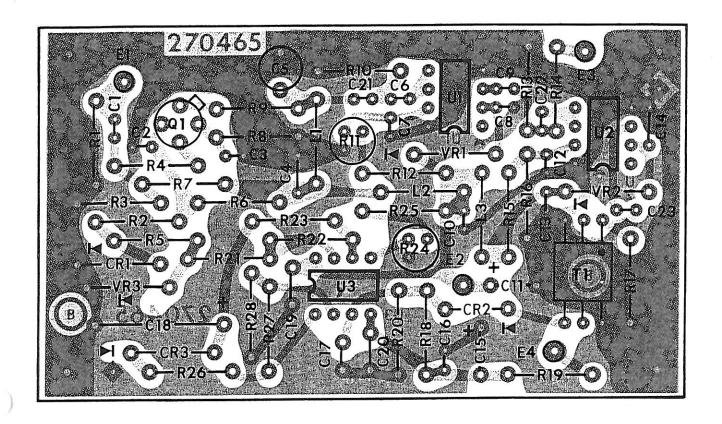


Figure F-3. Part 270465-1 Wideband IF Output Amplifier (A9A1), Location of Components

F.6.1.1 Part 270465-1, Wideband IF Output Amplifier

REF DESIG PREFIX A9A1

	1 at 2 2 2 2 1 2 1 2 1 3 1 1 2 2 2 2 2 2 2 2	101	REF D	ESIG PRE	FIX A9A1
REF DESIG	DESCRIPTION	QT' PEF ASS	MANUFACTURER'	S MFR.	RECM VENDOR
Ì	Revision E				
C1	Capacitor, Ceramic, Disc: 4700 pF, 20%, 50 V	13	8121-050-651-472M	59660	
C2	Same as C1		0121 000 001-412M	39060	
C3	Same as C1	- 1			
C4	Capacitor, Ceramic, Disc: 0.1 µF, 20%, 50 V	1	34475-1	14632	
C5	Capacitor, Variable, Ceramic: 5-25 pF, 100 V	1	518-000A5-25	59660	
C6	,			55000	
Thru C10	Same as C1		197		
C11	Capacitor, Electrolytic, Tantalum: 2.2 µF, 20%, 35 V				
C12	Same as C1	2	199D225X0035BE3	56289	
C13	Same as C1	1			1 1
C14	, , , , , , , , , , , , , , , , , , ,			1	
C15	Capacitor, Ceramic, Disc: 0.01 µF, 20%, 50 V Same as C11	1	34453-1	14632	
C16				1	
C17	Same as C1			1	
ı	Capacitor, Mica, Dipped: 330 pF, 2%, 100 V	1	CM04FA331G03	81349	1 1
C18	Capacitor, Electrolytic, Tantalum: 22 pF, 10%, 15 V	1	CS13BD226K	81349	
C19	Capacitor, Ceramic, Disc: 0.47 Fp, 20%, 50 V	2	34452-1	14632	
C20	Same as C19	1			
C21	Same as C1			I	1 1
C22	Capacitor, Ceramic, Monolithic: 47 pF, ±2%, 100 V	1	150-100-NPO-470G	51642	
C23 CR1	Same as C1				
CR1	Diode Diode	2	1N462A	80131	
CR3	000-5000-5000-5000-	1	5082-2800	28480	
L1	Same as CR1				1 1
	Coil, Fixed: 1.8 pH, 10%	1	1025-26	99800	
L2	Coil, Fixed: 18 pH, 10%	2	1025-50	99800	
L3	Same as L2				
Q1	Transistor	1	MFE211	04713	
R1	Resistor, Fixed, Film: 47Ω , $\pm 5\%$, $1/4$ W	3	CF1/4-47 OHMS/J	09021	
R2	Resistor, Fixed, Film: 33 kΩ, 5%, 1/4 W	1	CF1/4-33K/J	09021	
R3	Resistor, Fixed, Film: 10 kΩ, 5%, 1/4 W	2	CF1/4-10K/J	09021	
R4	Same as R1	1 1			
R5	Resistor, Fixed, Film: 4.7 k Ω , 5%, 1/4 W	2	CF1/4-4.7K/J	09021	
R6	Resistor, Fixed, Film: 100 kΩ, 5%, 1/4 W	2	CF1/4-100K/J	09021	
R7	Resistor, Fixed, Film: $68 \text{ k}\Omega$, 5%, $1/4 \text{ W}$	1	CF1/4-68K/J	09021	
R8	Resistor, Fixed, Film: 120Ω , 5%, 1/4 W	1	CF1/4-120 OHMS/J	09021	
R9	Resistor, Fixed, Film: 33Ω , 5%, 1/4 W	1	CF1/4-33 OHMS/J	09021	
R10	Resistor, Fixed, Film: 360Ω , 5%, 1/4 W	1	CF1/4-360 OHMS/J	09021	
R11	Resistor, Trimmer, Film: $5 \text{ k}\Omega$, 10% , $1/2 \text{ W}$	1	62PR5K	73138	
R12	Resistor, Fixed, Film: $22 k\Omega$, 5%, $1/4 W$	3	CF1/4-22K/J	09021	
R13	Resistor, Fixed, Film: 270Ω, 5%, 1/4 W	1	CF1/4-270 OHMS/J	09021	
			NA CONTRACTOR OF THE PROPERTY		

REF DESIG PREFIX A9A1

REF DESIG	DESCRIPTION	QTY PER ASSY	MANUFACTURER'S PART NO.	MFR. CODE	RECM VENDOR
R14	Same as R1				
R15	Same as R12		a a		
R16	Resistor, Fixed, Film: 3.3 kΩ, 5%, 1/4 W	1	CF1/4-3.3K/J	09021	
R17	Resistor, Fixed, Film: 220 kΩ, 5%, 1/4 W	1	CF1/4-220K/J	09021	
R18	Resistor, Fixed, Film: 150 kΩ, 5%, 1/4 W	1	CF1/4-150K/J	09021	
R19	Resistor, Fixed, Film: 100Ω, 5%, 1/4 W	1	CF1/4-100 OHMS/J	09021	
R20	Same as R5				
R21	Resistor, Fixed, Film: 1 kΩ, 5%, 1/4 W	1	CF1/4-1 K/J	09021	
R22	Resistor, Fixed, Film: 620 kΩ, 5%, 1/4 W	1	CF1/4-620K/J	09021	
R23	Same as R6				İ
R24	Resistor, Trimmer, Film: 100 kΩ, 10%, 1/2 W	1	62PR100K	73138	
R25	Same as R12				
R26	Resistor, Fixed, Film: 2.2 kΩ, 5%, 1/4 W	1	CF1/4-2.2K/J	09021	
R27	Resistor, Fixed, Film: 43 kΩ, 5%, 1/4 W	1	CF1/4-43K/J	09021	
R28	Same as R3		'		
T1	Transformer	1	T4-1	15542	
U1	Integrated Circuit	2	SL1611C/DP	52648	v
U2	Same as U1	I			- 10
U3	Integrated Circuit	1	MC1458N	18324	
VR1	Voltage Regulator: 8.2 V	2	1N756A	80131	1
VR2	Same as VR1				
VR3	Voltage Regulator: 6.3 V	1	1N753A	80131	

F.6.2 TYPE 724013-2, WIDEBAND IF OUTPUT AMPLIFIER

REF DESIG PREFIX A9

	REF DESIG PREFIX				DITIN MS
REF DESIG	DESCRIPTION	QTY PER ASSY	MANUFACTURER'S	MFR. CODE	RECM VENDOR
	Revision A				
A1	Wideband IF Output Amplifier (see Paragraph F.6.1.1)	1	270465-1	14632	1
C1	Capacitor, Ceramic, Feedthru: 1000 pF, GMV, 500 V	2	54-794-009-102W	33095	
C2	Same as C1				
C3	Capacitor, Mica, Dipped: 100 pF, 2%, 500 V	2	CM05FD101G03	81349	
C4	Capacitor, Ceramic, Standoff: 100 pF, 10%, 500 V	2	54-803-009-101K	33095	
C5	Capacitor, Mica, Dipped: 200 pF, 2%, 500 V	2	CM05FD201G03	81349	
C6	Capacitor, Ceramic, Tubular: 7.5 pF, ±0.5 pF, 500 V	1	301-000C0H0-759D	72982	
C7	Not Used				l i
C8	Same as C5				
C9	Same as C3			22	
C10	Same as C4			S.	
E1	Terminal, Fedthru	2	SFU16Y	1DM30	
E2	Same as E1	1			
J1	Connector, Receptacle	1	1012-1511-000	19505	
J2	Connector, Receptacle	1	1004-7511-002	19505	1
L1	Coil, Variable: 0.504-0.616 µH	2	558-7107-10	71279	- 1
L2	Coil, Variable: 7.38-9.02 µH	1	558-7107-24	71279	1
L3	Same as L1	- 1	1	- 1	
P1	Plug, Assembly	1	370434-4	14632	